

# QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 10-BIT LOW RESISTANCE BUS SWITCH WITH FLOW-THROUGH PINOUT

IDTQS3R861

### **FEATURES:**

- · Enhanced N channel FET with no inherent diode to Vcc
- 2.5 $\Omega$  bidirectional switches connect inputs to outputs
- · Zero propagation delay, zero ground bounce
- · Undershoot clamp diodes on all switch and control inputs
- Available in SOIC and QSOP packages

### **APPLICATIONS:**

- Hot-swapping, hot-docking (low resistance for PCI and Compact PCI applications)
- · Voltage translation (5V to 3.3V)
- Power Conservation
- · Capacitance reduction and isloation
- · Bus Isolation
- · Clock Gating

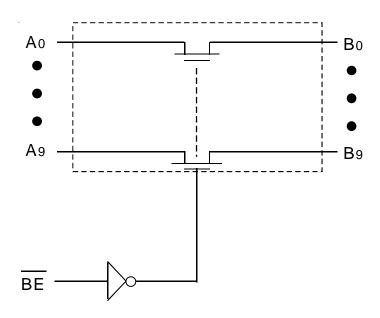
### **DESCRIPTION:**

The QS3R861 provides a set of ten high-speed CMOS TTL-compatible bus switches. The very low ON resistance (2.5 $\Omega$ ) of the QS3R861 allows inputs to be connected without adding propagation delay and without generating additional ground bounce noise. The Bus Enable ( $\overline{\text{BE}}$ ) signal turns the switches on.

The low ON resistance of the QS3R861 makes it ideal for PCI hot-plugging or hot-swapping applications.

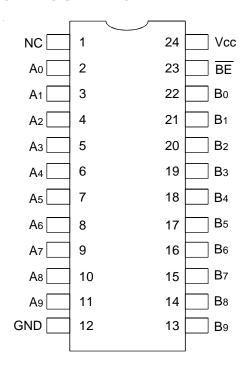
The QS3R861 is characterized for operation at -40°C to +85°C.

# FUNCTIONAL BLOCK DIAGRAM



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### **PIN CONFIGURATION**



SOIC/ QSOP TOP VIEW

## ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	-0.5 to +7	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to +7	V
VTERM <sup>(3)</sup>	DC Input Voltage VIN	-0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
Іоит	DC Output Current	120	mA
Рмах	Maximum Power Dissipation	0.5	W
Tstg	Storage Temperature	-65 to +150	°C

#### NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc .

## CAPACITANCE (TA = +25°C, f = 1MHz, VIN = 0V, VOUT = 0V)

Pins	Тур.	Max. <sup>(1)</sup>	Unit
Control Inputs	3	4	рF
Quickswitch Channels (Switch OFF)	5	6	рF

#### NOTE:

1. This parameter is guaranteed but not production tested.

### **PIN DESCRIPTION**

Pin Names	Description
A0 - A9	Bus A
B0 - B9	Bus B
ΒĒ	Bus Switch Enable

## FUNCTION TABLE(1)

BE	Ao - Ao Functio	
Н	Z	Disconnect
L	Bo - B9	Connect

#### NOTF.

- 1. H = HIGH Voltage Level
  - L = LOW Voltage Level
  - Z = High-Impedance

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

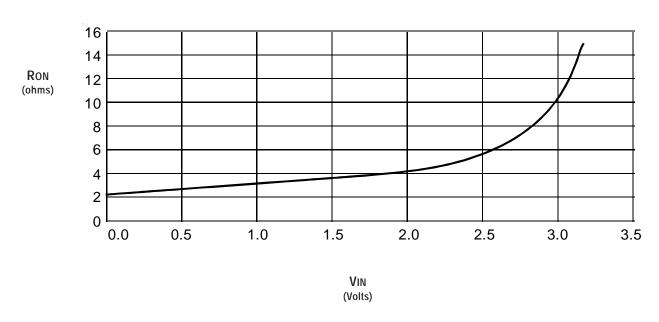
Industrial: TA = -40°C to +85°C, VCC =  $5V \pm 10\%$ 

Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	_	_	V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	_	_	8.0	V
lin	Input Leakage Current (Control Inputs)	0V ≤ Vin ≤ Vcc	_	0.01	±1	μA
loz	Off-State Current (Hi-Z)	0V ≤ Vout ≤ Vcc, Switches OFF	_	0.01	±1	μA
Ron	Switch ON Resistance <sup>(2)</sup>	Vcc = Min., VIN = 0V, ION = 30mA	_	2.5	5	Ω
		VCC = Min., VIN = 2.4V, ION = 15mA	_	4	8.5	
VP	Pass Voltage <sup>(3)</sup>	$VIN = VCC = 5V$ , $IOUT = -5\mu A$	3.7	4	4.3	V

#### NOTES:

- 1. Typical values are at Vcc = 5V and TA = 25°C.
- 2. Max value of Ron is guaranteed but not production tested.
- 3. Pass voltage is guaranteed but not production tested.

# TYPICAL ON RESISTANCE vs Vin AT Vcc = 5V



### HIGH-SPEED CMOS 10-BIT LOW RESISTANCE BUS SWITCH

## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Typ. <sup>(2)</sup>	Max.	Unit
Icco	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc, f = 0	0.2	3	μА
∆lcc	Power Supply Current per Input HIGH <sup>(3)</sup>	Vcc = Max., Vin = 3.4V, f = 0		2.5	mA
ICCD	Dynamic Power Supply Current per MHz <sup>(4)</sup>	Vcc = Max., A and B Pins Open,  BE Input Toggling @ 50% Duty Cycle	_	0.25	mA/MHz

#### NOTES:

- 1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- 2. Typical values are at Vcc = 5V and TA = 25°C.
- 3. Per TTL-driven input ( $V_{IN} = 3.4V$ , control inputs only). A and B pins do not contribute to  $\Delta lcc$ .
- 3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_A = -40^{\circ}C \text{ to } +85^{\circ}C, V_{CC} = 5V \pm 10\%$ 

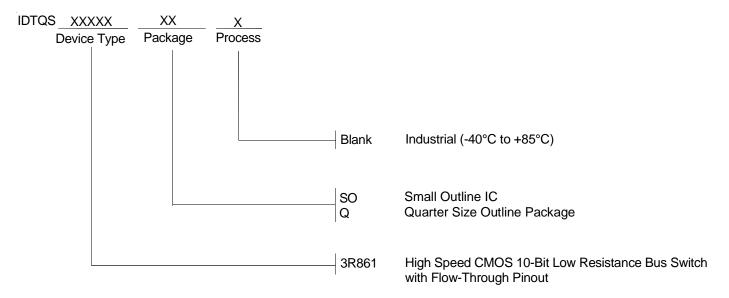
CLOAD = 50pF, RLOAD =  $500\Omega$  unless otherwise noted.

Symbol	Parameter	Min. <sup>(1)</sup>	Тур.	Max.	Unit
tplh	Data Propagation Delay <sup>(2)</sup>	_	_	0.12 <sup>(3)</sup>	ns
tphl	A to B, B to A				
tPZL	Switch Turn-On Delay	1.5	_	5.6	ns
tpzh	BE to A or B				
tPLZ	Switch Turn-Off Delay <sup>(2)</sup>	1.5	_	4.5	ns
tphz	BE to A or B				

#### NOTES:

- 1. Minimums are guaranteed but not production tested.
- 2. This parameter is guaranteed but not production tested.
- 3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.12ns at C<sub>L</sub> = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

# ORDERING INFORMATION





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